查询AS7C32098A-10TC供应商

捷多邦,专业PCB打样工厂,24小时加急出货

February 2005 Preliminary Information

AS7C32098A

3.3 V 128K × 16 CMOS SRAM

Features

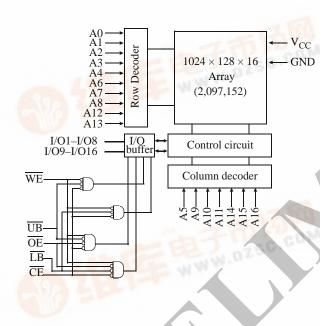
- Industrial and commercial temperature
- Organization: 131,072 words $\times 16$ bits
- Center power and ground pins
- High speed
- 10/12/15/20 ns address access time
- 4/5/6/7 ns output enable access time
- Low power consumption: ACTIVE
- 650 mW /max @ 10 ns
- Low power consumption: STANDBY

Logic block diagram

- 28.8 mW /max CMOS

- Individual byte read/write controls
- Easy memory expansion with \overline{CE} , \overline{OE} inputs
- TTL- and CMOS-compatible, three-state I/O
- 44-pin JEDEC standard packages
- TSOP 2
 ESD protection ≥ 2000 volts
- Latch-up current $\geq 200 \text{ mA}$

Pin arrangement for TSOP 2



allangei	пспі	101 190	4012	
	12			
A0		10	44	A16
A1		2	43	A15
A2		23	42	A14
A3		4	41	OE
A4		5	40	UB
CE		6	39	LB
I/O1		7	38	I/O16
I/O2		8	37	I/O15
I/O3		9	36	I/O14
I/O4		10	35	I/O13
V _{CC}		11	34	GND
GND		12	33	V _{CC}
I/05		13	32	I/Õ12
I/O6		14	31	I/O11
I/07		15	30	I/O10
I/O8		16	29	I/O9
WE		17	28	NC
A5		18	27	A13
A6		19	26	A12
A7		20	25	A11
A8		21	24	A10
A9		22	23	NC
	5.0		W.075	

Selection guide

2/24/05 v

"为子伊!	COM	-10	-12	-15	-20	Unit
Maximum address access time		10	12	15	20	ns
Maximum output enable access time	4	5	6	7	ns	
Maximum operating current	Industrial	180	160	140	110	mA
Maximum operating current	Commercial	170	150	130	100	mA
Maximum CMOS standby current		8	8	8	8	mA

®

Functional description

The AS7C32098A is a high-performance CMOS 2,097,152-bit Static Random Access Memory (SRAM) device organized as 131,072 words \times 16 bits. It is designed for memory applications where fast data access, low power, and simple interfacing are desired.

Equal address access and cycle times (t_{AA} , t_{RC} , t_{WC}) of 10/12/15/20 ns with output enable access times (t_{OE}) of 4/5/6/7 ns are ideal for high-performance applications. The chip enable input \overline{CE} permits easy memory expansion with multiple-bank memory systems.

When $\overline{\text{CE}}$ is high the device enters standby mode. The device is guaranteed not to exceed 28.8mW power consumption in CMOS standby mode. A write cycle is accomplished by asserting write enable ($\overline{\text{WE}}$) and chip enable ($\overline{\text{CE}}$). Data on the input pins I/O1–I/O16 is written on the rising edge of $\overline{\text{WE}}$ (write cycle 1) or $\overline{\text{CE}}$ (write cycle 2). To avoid bus contention, external devices should drive I/O pins only after outputs have been disabled with output enable ($\overline{\text{OE}}$) or write enable ($\overline{\text{WE}}$).

A read cycle is accomplished by asserting output enable (\overline{OE}) and chip enable (\overline{CE}), with write enable (\overline{WE}) high. The chip drives I/O pins with the data word referenced by the input address. When either chip enable or output enable is inactive, or write enable is active, output drivers stay in high-impedance mode.

The device provides multiple center power and ground pins, and separate byte enable controls, allowing individual bytes to be written and read. \overline{LB} controls the lower bits, I/O1–I/O8, and \overline{UB} controls the higher bits, I/O9–I/O16.

All chip inputs and outputs are TTL- and CMOS-compatible, and operation is for 3.3V (AS7C32098A) supply. The device is available in the JEDEC standard TSOP 2 package.

Parameter	Symbol	Min	Max	Unit
Voltage on V _{CC} relative to GND	V _{t1}	-0.50	+5.0	V
Voltage on any pin relative to GND	V _{t2}	-0.50	V _{CC} +0.50	V
Power dissipation	PD	-	1.5	W
Storage temperature (plastic)	T _{stg}	-65	+150	°C
Ambient temperature with V _{CC} applied	T _{bias}	-55	+125	°C
DC current into outputs (low)	I _{OUT}	-	±20	mA

Absolute maximum ratings

Note: Stresses greater than those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Truth table

CE	WE	OE	LB	UB	I/O1–I/O8	I/O9–I/O16	Mode
Н	Х	X	Х	Х	High Z	High Z	Standby (I _{SB} , I _{SB1})
L	Н	Н	Х	Х	High 7	High 7	Output dischle (I)
L	Х	Х	Н	Н	High Z	High Z	Output disable (I _{CC})
			L	Н	D _{OUT}	High Z	
L	Н	H L	Н	L	High Z	D _{OUT}	Read (I _{CC})
			L	L	D _{OUT}	D _{OUT}	
			L	Н	D _{IN}	High Z	
L	L	Х	Н	L	High Z	D _{IN}	
			L	L	D _{IN}	D _{IN}	Write (I _{CC})

Key: X = Don't care, L = Low, H = High.

Recommended operating conditions

Parameter		Symbol	Min	Typical	Max	Unit
Supply voltage		V _{CC} (10/12/15/20)	3.0	3.3	3.6	V
Input voltage		V_{IH}^{**}	2.0	_	$V_{CC} + 0.5$	V
input voltage		V_{IL}^{*}	-0.5	_	0.8	V
Ambient operating temperature	commercial	T _A	0	_	70	°C
	industrial	T _A	-40	-	85	°C

 ${}^{*}_{**}V_{IL} \min = -1.0V \text{ for pulse width less than 5ns.}$ $V_{IH} \max = V_{CC} + 2.0V \text{ for pulse width less than 5ns.}$

DC operating characteristics (over the operating range)¹

				_]	10	_	12	_	15	Ť	20	
Parameter	Symbol	Test conditions		Min	Max	Min	Max	Min	Max	Min	Max	Unit
Input leakage current	$ \mathbf{I}_{LI} $	V _{CC} = Max V _{IN} = GND to V ₀	cc		1	_	1	_	1	_	1	μA
Output leakage current	I _{LO}	$V_{CC} = Max$ $\overline{CE} = V_{\underline{IH}} \text{ or } \overline{OE} =$ or $\overline{WE} = V_{IL}$ $V_{I/O} = GND \text{ to } V_{I/O}$			1	-	1	_	1	_	1	μΑ
Operating power supply current	I _{CC}	$V_{CC} = Max$ $\overline{CE} \le V_{IL}, f = f_{max} I_{OUT} = 0mA$	Industrial Commercial	-	180 170	-	160 150	-	140 130	-	110 100	mA mA
G(I _{SB}	$\frac{V_{CC} = Max}{\overline{CE} \ge V_{IH}, f = Ma}$	ıx	-	60	-	60	-	60	-	60	mA
Standby power supply current	I _{SB1}	$V_{CC} = Max$ $\overline{CE} \ge V_{CC} - 0.2V, V_{IN} \ge V_{CC}$ $V_{IN} \le 0.2V, f = 0$		_	8	_	8	_	8	_	8	mA
Output voltage	V _{OL}	$I_{OL} = 8 \text{ mA}, V_{CC} =$	Min	1	0.4	-	0.4	-	0.4	-	0.4	V
Sulput Voluge	V _{OH}	$I_{OH} = -4 \text{ mA}, \text{ V}_{CC} =$	Min	2.4	_	2.4	_	2.4	-	2.4	-	V

Capacitance (f = 1MHz, $T_a = 25^{\circ} \text{ C}$, $V_{CC} = \text{NOMINAL})^4$

Parameter	Symbol	Signals	Test conditions	Max	Unit
Input capacitance	C _{IN}	A, \overline{CE} , \overline{WE} , \overline{OE} , \overline{UB} , \overline{LB}	$V_{IN} = 0V$	6	pF
I/O capacitance	C _{I/O}	I/O	$V_{IN} = V_{OUT} = 0V$	8	pF

ß

Read cycle (over the operating range)^{2,8}

		-10		-1	12	-15		-20			
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Min	Max	Unit	Notes
Read cycle time	t _{RC}	10	_	12	-	15	-	20	-	ns	
Address access time	t _{AA}	_	10	_	12	-	15	_	20	ns	
Chip enable (\overline{CE}) access time	t _{ACE}	-	10	_	12	_	15	_	20	ns	
Output enable (\overline{OE}) access time	t _{OE}	-	4	-	5	-	6	-	7	ns	
Output hold from address change	t _{OH}	3	_	3	_	3	-	3	-	ns	4
$\overline{\text{CE}}$ Low to output in low Z	t _{CLZ}	3	-	3	_	3	-	3	- >	ns	3,4
$\overline{\text{CE}}$ High to output in high Z	t _{CHZ}	-	5	-	6	-	7	-	9	ns	3,4
\overline{OE} Low to output in low Z	t _{OLZ}	0	_	0	_	0	-	0	-	ns	3,4
$\overline{\text{OE}}$ High to output in high Z	t _{OHZ}	-	5	_	6	-	7	-	9	ns	3,4
$\overline{\text{LB}}, \overline{\text{UB}}$ access time	t _{BA}	-	5	-	6	-	7	_	8	ns	
$\overline{\text{LB}}, \overline{\text{UB}}$ Low to output in low Z	t _{BLZ}	0	_	0	-	0	_	0	-	ns	
$\overline{\text{LB}}, \overline{\text{UB}}$ High to output in high Z	t _{BHZ}	-	5	-	6	-	7	_	9	ns	
Power up time	t _{PU}	0	- F	0	-	0	_	0	-	ns	4
Power down time	t _{PD}		10	-	12	-	15	-	20	ns	4

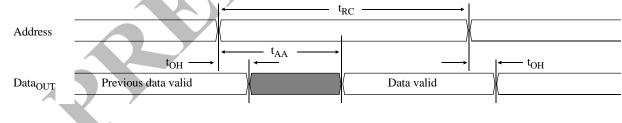
Key to switching waveforms

Rising input

Falling input

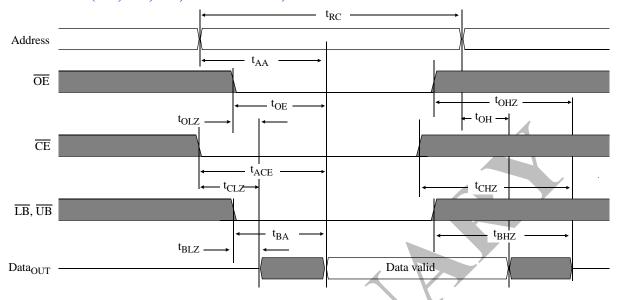
Undefined/don't care

Read waveform 1 (address controlled)^{5,6,8}



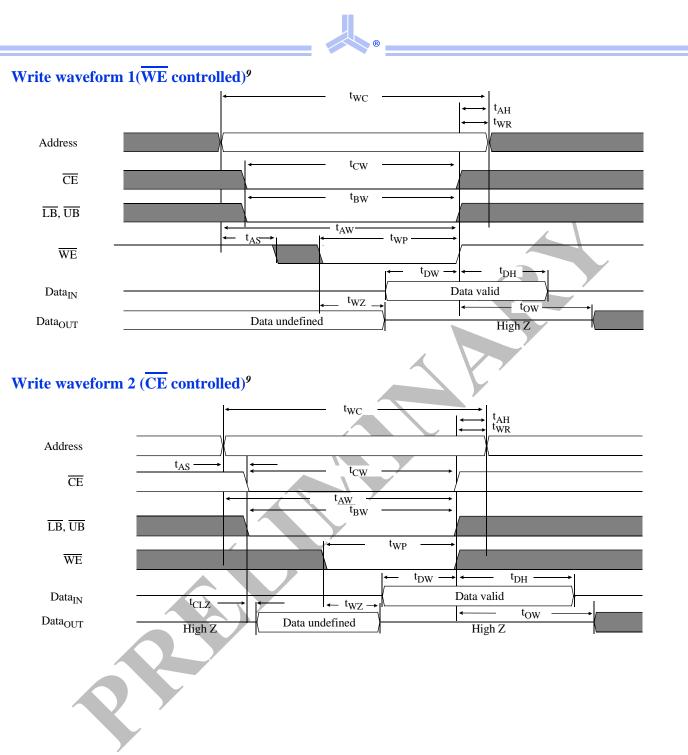
®

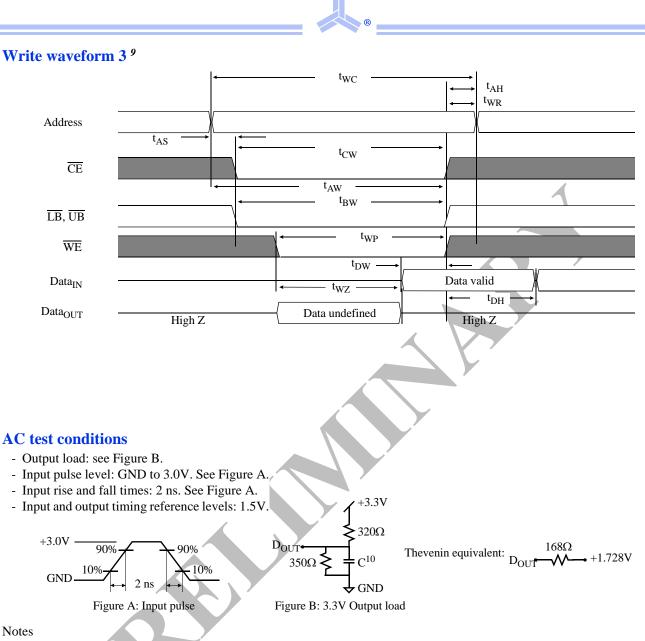
Read waveform 2 (\overline{CE} , \overline{OE} , \overline{UB} , \overline{LB} controlled)^{5,7,8}



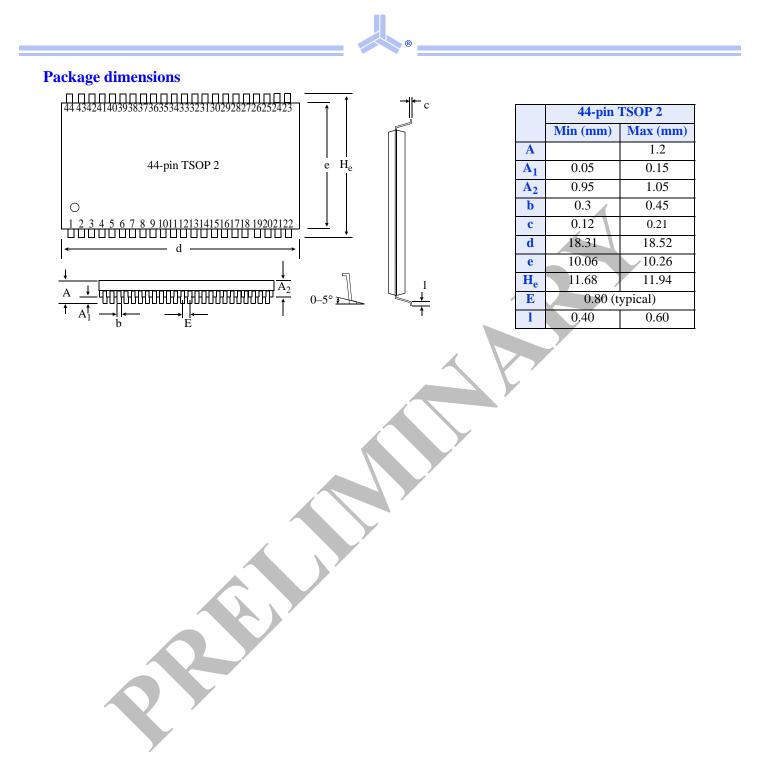
Write cycle (over the operating range)⁹

		_	-10 -12		_	15	-20				
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Min	Max	Unit	Note
Write cycle time	t _{WC}	10		12	-	15	_	20	_	ns	
Chip enable $\overline{(CE)}$ to write end	t _{CW}	7	ł	8	-	10	_	12	_	ns	
Address setup to write end	t _{AW}	7	-)	8	-	10	_	12	-	ns	
Address setup time	t _{AS}	0	> -	0	-	0	_	0	_	ns	
Write pulse width ($\overline{OE} = High$)	t _{WP1}	7	-	8	-	10	_	12	_	ns	
Write pulse width ($\overline{OE} = Low$)	t _{WP2}	10	-	12	-	15	_	20	_	ns	
Write recovery time	t _{WR}	0	-	0	-	0	_	0	-	ns	
Address hold from end of write	t _{AH}	0	-	0	-	0	_	0	-	ns	
Data valid to write end	t _{DW}	5	-	6		7	_	9	_	ns	
Data hold time	t _{DH}	0	-	0	-	0	_	0	-	ns	3,4
Write enable to output in High-Z	t _{WZ}	0	5	0	6	0	7	0	9	ns	3,4
Output active from write end	t _{OW}	3	-	3	_	3	—	3	_	ns	3,4
Byte enable Low to write end	t _{BW}	7	_	8	—	10		12	_	ns	3,4





- During V_{CC} power-up, a pull-up resistor to V_{CC} on \overline{CE} is required to meet I_{SB} specification. 1
- 2 For test conditions, see AC Test Conditions, Figures A and B.
- t_{CLZ} and t_{CHZ} are specified with $C_L = 5pF$ as in Figure B. Transition is measured $\pm 500mV$ from steady-state voltage. 3
- 4 This parameter is guaranteed, but not tested.
- 5 $\overline{\text{WE}}$ is High for read cycle.
- \overline{CE} and \overline{OE} are Low for read cycle. 6
- 7 Address valid prior to or coincident with \overline{CE} transition Low.
- 8 All read cycle timings are referenced from the last valid address to the first transitioning address.
- 9 All write cycle timings are referenced from the last valid address to the first transitioning address.
- 10 C=30pF, except on High Z and Low Z parameters, where C=5pF.



ß

Ordering Codes

Package	Temperature	10 ns	12 ns	15 ns	20 ns
TSOP 2	Commercial	AS7C32098A-10TC	AS7C32098A-12TC	AS7C32098A-15TC	AS7C32098A-20TC
	Industrial	AS7C32098A-10TI	AS7C32098A-12TI	AS7C32098A-15TI	AS7C32098A-20TI

Note: Add suffix 'N' to the above part numbers for Lead Free Parts. (Ex: AS7C32098A - 10TCN)

Part numbering system

					*	
AS7C	X	2098A	-XX	Т	Х	X
SRAM prefix	Voltage: 3 - 3.3V CMOS		Access time	Package: T: TSOP 2	Temperature ranges: C: Commercial, 0°C to 70°C I: Industrial, -40°C to 85°C	N = Lead Free Parts





Alliance Semiconductor Corporation 2575, Augustine Drive, Santa Clara, CA 95054 Tel: 408 - 855 - 4900 Fax: 408 - 855 - 4999

www.alsc.com

Copyright © Alliance Semiconductor All Rights Reserved Preliminary Information Part Number: AS7C32098A Document Version: v. 1.0

© Copyright 2003 Alliance Semiconductor Corporation. All rights reserved. Our three-point logo, our name and Intelliwatt are trademarks or registered trademarks of Alliance. All other brand and product names may be the trademarks of their respective companies. Alliance reserves the right to make changes to this document and its products at any time without notice. Alliance assumes no responsibility for any errors that may appear in this document. The data contained herein represents Alliance's best data and/or estimates at the time of issuance. Alliance reserves the right to change or correct this data at any time, without notice. If the product described herein is under development, significant changes to these specifications are possible. The information in this product data sheet is intended to be general descriptive information for potential customers and users, and is not intended to operate as, or provide, any guarantee or warrantee to any user or customer. Alliance does not assume any responsibility or liability arising out of the application or use of any product described herein, and disclaims any express or implied warranties related to the sale and/or use of Alliance products including liability or warranties related to fitness for a particular purpose, merchantability, or infringement of any intellectual property rights, except as express agreed to in Alliance's Terms and Conditions of Sale (which are available from Alliance). All sales of Alliance products are made exclusively according to Alliance's Terms and Conditions of Sale. The purchase of products from Alliance does not convey a license under any patent rights, copyrights; mask works rights, trademarks, or any other intellectual property rights of the inclusion of Alliance or third parties. Alliance does not authorize its products for use as critical components in life-supporting systems where a malfunction or failure may reasonably be expected to result in significant injury to the user, and the inclusion of Alliance products in such life s